

RJK03E7DPA

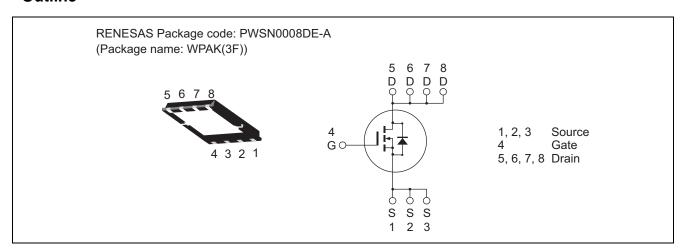
30V, 45A, $2.8m\Omega$ max. N Channel Power MOS FET High Speed Power Switching

R07DS0933EJ0400 Rev.4.00 Mar 22, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V_{GSS}	±12	V
Drain current	I _D	45	А
Drain peak current	I _{D(pulse)} Note1	180	A
Body-drain diode reverse drain current	I _{DR}	45	A
Avalanche current	I _{AP} Note 2	22	A
Avalanche energy	E _{AR} Note 2	48.4	mJ
Channel dissipation	Pch Note3	45	W
Channel to case thermal impedance	θch-c Note3	2.78	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. $Tc = 25^{\circ}C$

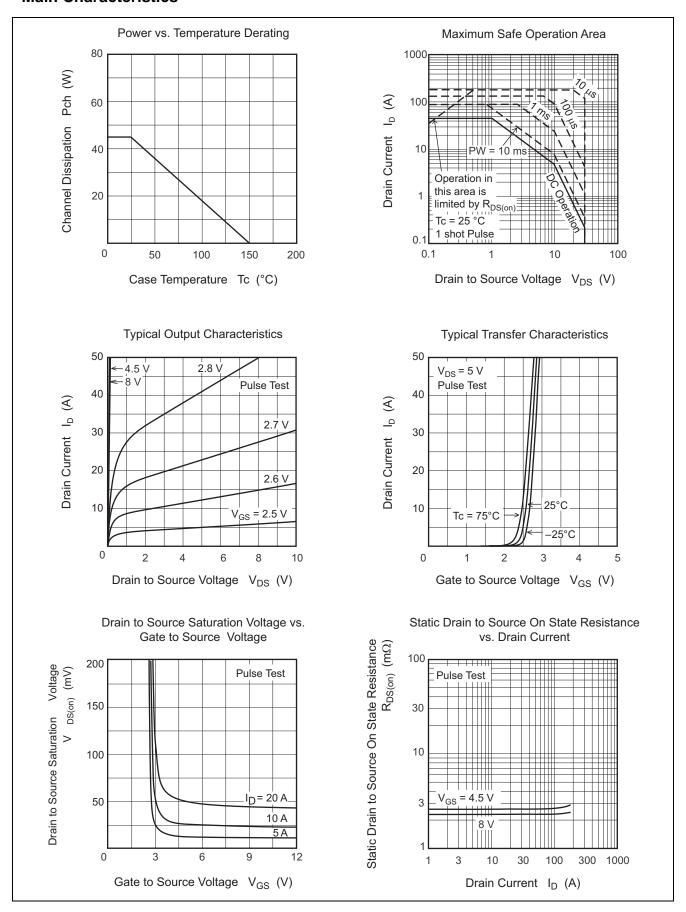
Electrical Characteristics

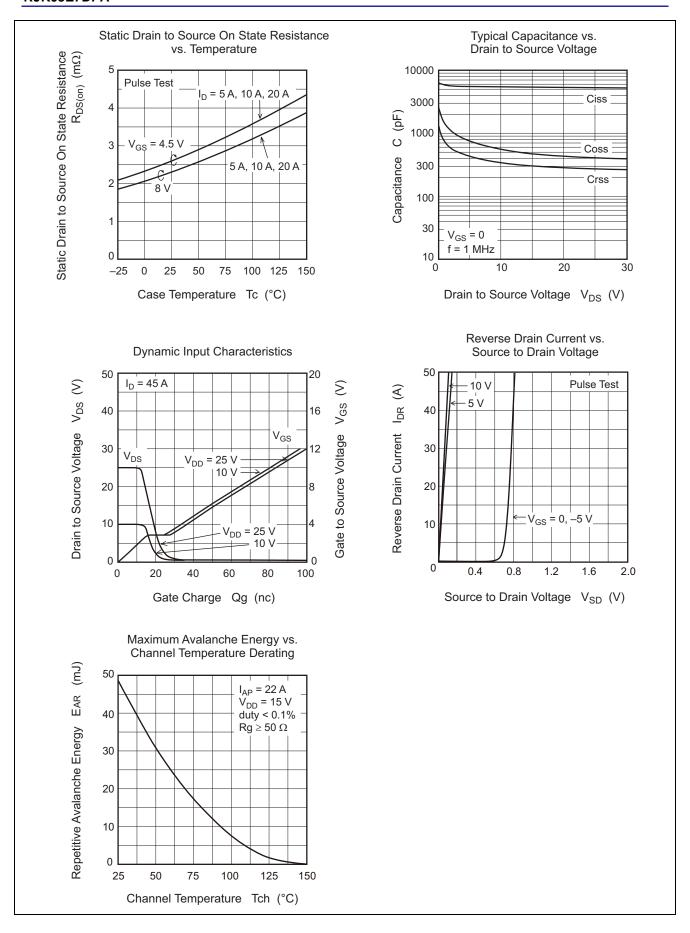
 $(Ta = 25^{\circ}C)$

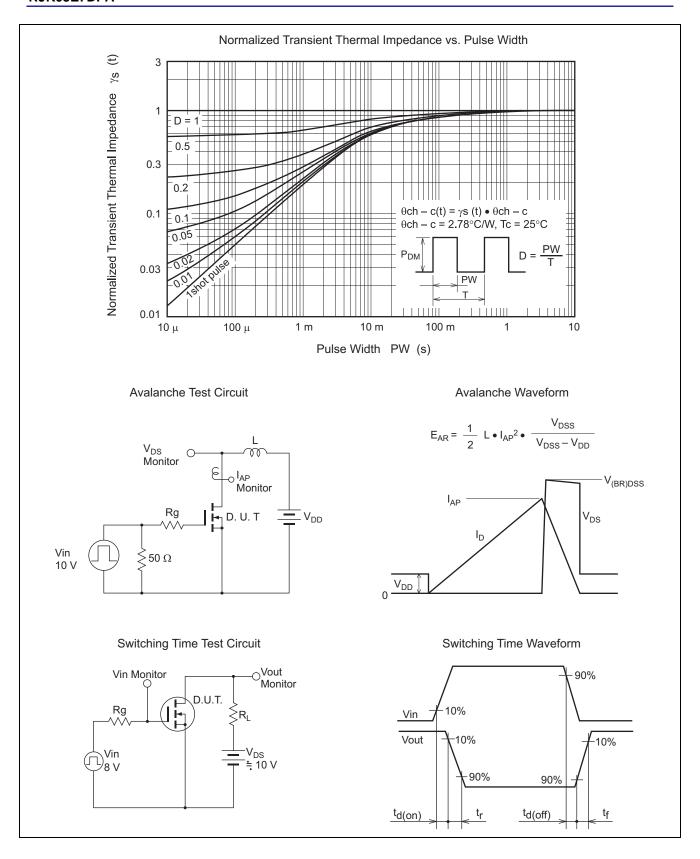
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	± 0.1	μΑ	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}		2.3	2.8	mΩ	$I_D = 22.5 \text{ A}, V_{GS} = 8.0 \text{ V}^{Note4}$
resistance	R _{DS(on)}		2.6	3.3	mΩ	$I_D = 22.5A, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}		120	_	S	$I_D = 22.5 \text{ A}, V_{DS} = 5 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss		5390	7450	pF	V _{DS} = 10 V
Output capacitance	Coss		560	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss		340	_	pF	f = 1 MHz
Gate Resistance	Rg		0.71	1.9	Ω	
Total gate charge	Qg	_	36	_	nC	V _{DD} = 10 V
Gate to source charge	Qgs	_	16	_	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	Qgd	_	11	_	nC	I _D = 45 A
Turn-on delay time	t _{d(on)}	_	22	_	ns	$V_{GS} = 8 \text{ V}, I_D = 22.5 \text{ A}$
Rise time	t _r		7.7	_	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	t _{d(off)}		63	_	ns	$R_L = 0.44 \Omega$
Fall time	t _f		12.5	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	0.80	1.04	V	$I_F = 45 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	_	26	_	ns	$I_F = 45 \text{ A}, V_{GS} = 0$ $di_F / dt = 100 \text{ A} / \mu \text{s}$

Notes: 4. Pulse test

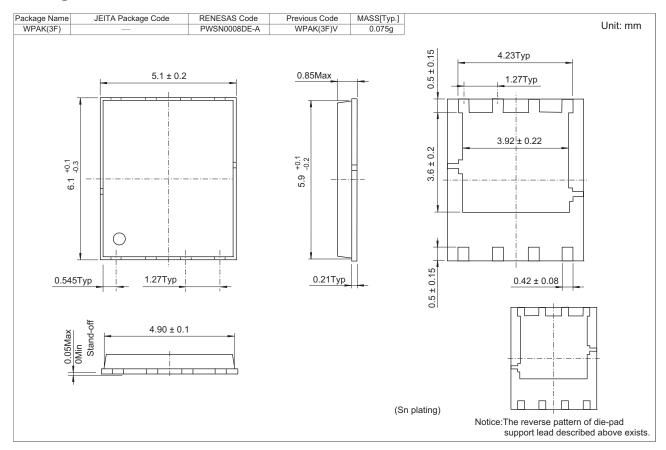
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK03E7DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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